### 2N2221A 2N2222A

# SILICON NPN TRANSISTORS



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**UNITS** 

V

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### **DESCRIPTION:**

**SYMBOL** 

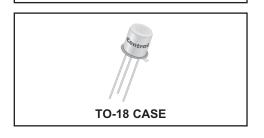
V<sub>CBO</sub>

The CENTRAL SEMICONDUCTOR 2N2221A and 2N2222A are silicon NPN epitaxial planar transistors designed for small signal, general purpose switching applications.

75

40

**MARKING: FULL PART NUMBER** 



**MAXIMUM RATINGS**: (T<sub>A</sub>=25°C)

Collector-Base Voltage

Collector-Emitter Voltage

	3.	CLO					
Emitter-Base	Voltage	$V_{EBO}$		6.	.0		V
Continuous Co	ollector Current	IC		80	00		mA
Power Dissipa	ation	$P_{D}$		50	00		mW
Power Dissipa	ation (T <sub>C</sub> =25°C)	$P_{D}$		1.	.8		W
Operating and	Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>		-65 to	+200		°C
Thermal Resis	stance	$\Theta_{JA}$		35	50	c	°C/W
Thermal Resis	stance	$\Theta$ JC		9	7	c	°C/W
ELECTRICAL	. CHARACTERISTICS: (T <sub>A</sub> =25°C u	nless otherwi	ise not	ed)			
SYMBOL	TEST CONDITIONS	MIN		MA		U	INITS
I <sub>CBO</sub>	V <sub>CB</sub> =60V			1			nA
<sup>I</sup> СВО	V <sub>CB</sub> =60V, T <sub>A</sub> =150°C			1	-		μA
ICEV	$V_{CE}$ =60V, $V_{EB}$ =3.0V			1			nA
I <sub>EBO</sub>	V <sub>EB</sub> =3.0V			1	0		nA
BV <sub>CBO</sub>	I <sub>C</sub> =10μA	75					V
BVCEO	I <sub>C</sub> =10mA	40					V
BVEBO	I <sub>E</sub> =10μA	6.0					V
V <sub>CE</sub> (SAT)	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA			0.	.3		V
VCE(SAT)	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA			1.	.0		V
V <sub>BE</sub> (SAT)	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA	0.6		1.	2		V
V <sub>BE</sub> (SAT)	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA			2.			V
			<u>2N22</u> /IIN	221 <u>A</u> MAX	2N2 MIN	<u>222A</u> MAX	
h <sub>FE</sub>	V <sub>CF</sub> =10V, I <sub>C</sub> =0.1mA		/IIN 20	WAX	35	IVIAA	
hFE	V <sub>CE</sub> =10V, I <sub>C</sub> =1.0mA		25	_	50	_	
h <sub>FE</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA		35	_	75	_	
h <sub>FE</sub>	V <sub>CF</sub> =10V, I <sub>C</sub> =10mA, T <sub>A</sub> =-55°C		15	_	35	_	
	V <sub>CE</sub> =10V, I <sub>C</sub> =150mA		40	120	100	300	
h <sub>FE</sub>	V <sub>CE</sub> =1.0V, I <sub>C</sub> =150mA		20	-	50	-	
h <sub>FE</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =500mA		25 25	_	40	_	
hFE	VCE-10 V, 1℃-300111A	•	20	-		- R5 (5-De	acamh,

R5 (5-December 2013)

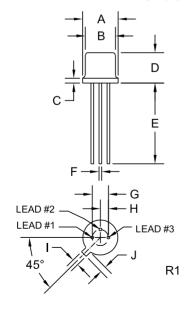
### 2N2221A 2N2222A

### SILICON NPN TRANSISTORS



ELECTRICAL CHARACTERISTICS - Continued: (T <sub>A</sub> =25°C) 2N2221A			221A	2N2		
SYMBOL	TEST CONDITIONS	MIN	MAX	MIN	MAX	UNITS
$f_T$	$V_{CE}$ =20V, $I_{C}$ =20mA, f=100MHz	250	-	300	-	MHz
$C_{ob}$	$V_{CB}$ =10V, $I_{E}$ =0, f=100kHz	-	8.0	-	8.0	pF
C <sub>ib</sub>	$V_{EB}$ =0.5V, $I_{C}$ =0, f=100kHz	-	25	-	25	pF
h <sub>ie</sub>	$V_{CE}$ =10V, $I_{C}$ =1.0mA, f=1.0kHz	1.0	3.5	2.0	8.0	kΩ
h <sub>ie</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA, f=1.0kHz	0.2	1.0	0.25	1.25	kΩ
h <sub>re</sub>	$V_{CE}$ =10V, $I_{C}$ =1.0mA, f=1.0kHz	-	5.0	-	8.0	x10 <sup>-4</sup>
h <sub>re</sub>	$V_{CE}$ =10V, $I_{C}$ =10mA, f=1.0kHz	-	2.5	-	4.0	x10 <sup>-4</sup>
h <sub>fe</sub>	$V_{CE}$ =10V, $I_{C}$ =1.0mA, f=1.0kHz	30	150	50	300	
h <sub>fe</sub>	$V_{CE}$ =10V, $I_{C}$ =10mA, f=1.0kHz	50	300	75	375	
h <sub>oe</sub>	$V_{CE}$ =10V, $I_{C}$ =1.0mA, f=1.0kHz	3.0	15	5.0	35	μS
h <sub>oe</sub>	$V_{CE}$ =10V, $I_{C}$ =10mA, f=1.0kHz	10	100	25	200	μS
rb'C <sub>C</sub>	$V_{CB}$ =10V, $I_E$ =20mA, f=31.8MHz	-	150	-	150	ps
NF	$V_{CE}$ =10V, $I_{C}$ =100 $\mu$ A, $R_{S}$ =1.0 $k\Omega$ , f=1.0 $kHz$	-	-	-	4.0	dB
$t_d$	$V_{CC}$ =30V, $V_{BE}$ =0.5V, $I_{C}$ =150mA, $I_{B1}$ =15mA	-	10	-	10	ns
t <sub>r</sub>	$V_{CC}$ =30V, $V_{BE}$ =0.5V, $I_{C}$ =150mA, $I_{B1}$ =15mA	-	25	-	25	ns
$t_S$	$V_{CC}$ =30V, $I_{C}$ =150mA, $I_{B1}$ = $I_{B2}$ =15mA	-	225	-	225	ns
t <sub>f</sub>	$V_{CC}$ =30V, $I_{C}$ =150mA, $I_{B1}$ = $I_{B2}$ =15mA	-	60	-	60	ns

# **TO-18 CASE - MECHANICAL OUTLINE**



DIMENSIONS						
	INC	HES	MILLIMETERS			
SYMBOL	MIN	MAX	MIN	MAX		
A (DIA)	0.209	0.230	5.31	5.84		
B (DIA)	0.178	0.195	4.52	4.95		
С	-	0.030	-	0.76		
D	0.170	0.210	4.32	5.33		
Е	0.500	-	12.70	-		
F (DIA)	0.016	0.019	0.41	0.48		
G (DIA)	0.100		2.54			
Н	0.050		1.27			
I	0.036	0.046	0.91	1.17		
J	0.028	0.048	0.71	1.22		

TO-18 (REV: R1)

#### **LEAD CODE:**

- 1) Emitter
- 2) Base
- 3) Collector

MARKING: FULL PART NUMBER

R5 (5-December 2013)